

General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

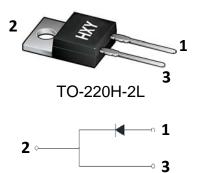
Features

- Low conduction loss due to low VF
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

Applications

- UPS
- Power Inverter
- High performance SMPS
- Power factor correction

Ordering Part Number	Package	Qty(PCS)	
HIDH16G65C5	TO-220H-2L	50	RoHS Post



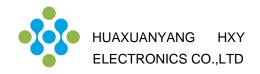


Maximum Ratings (at Tj = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	Vrrm	650	V
Surge Peak Reverse Voltage	Vrsm	650	V
DC Peak Reverse Voltage	Vr	650	V
Continuous Forward Current Tc = 25°C		47	
$T_{c} = 135^{\circ}C$ $T_{c} = 160^{\circ}C$	lF	24 16	A
Repetitive Peak Forward Surge Current $Tc = 25^{\circ}C, t_{p}=10ms, Half Sine Pulse$ $Tc = 110^{\circ}C, t_{p}=10ms, Half Sine Pulse$	IFRM	70 56	А
Non-Repetitive Forward Surge Current $Tc = 25^{\circ}C, t_{p}=10ms, Half Sine Pulse$ $Tc = 110^{\circ}C, t_{p}=10ms, Half Sine Pulse$	IFSM	128 98	A
i²dt value Tc = 25°C,t _P =10ms,Half Sine Pulse Tc = 110°C,t _P =10ms,Half Sine Pulse	∫ i²dt	81 48	A²s
Power dissipation Tc = 25°C Tc = 110°C	Ptot	115 50	w
Operating junction Range	Tj	-55 to +175	°C
Storage temperature Range	Tstg	-55 to +150	°C

Thermal Resistance

Parameter	Symbol	Value	Unit
Thermal resistance, junction – case.	RthJC	1.30	°C/W



Parameter	Symbol		Value		Unit	Test Condition	
Falametei	Symbol	min.	typ.	max.	Onit		
						I⊧=16A	
Forward Voltage	Vf	-	1.3	1.5	V	Tj=25°C	
		-	1.5	-		Tj=175°C	
						VR=650V	
Reverse Current	Ir	-	-	100	μA	Tj=25°C	
		-	-	200		Tj=175°C	
						V ≈=400V,Tj=25 ℃	
Total Capacitive Charge	Qc	-	52	-	nC	$Q_{C} = \int_{0}^{V_{R}} C(V) dV$	
Total Capacitance	С				pF	Tj =25 ℃, f=1MHz	
		-	993	-		Vr=0V	
		-	101	-		VR=200V	
		-	83	-		VR=400V	

Electrical Characteristic (at Tj = 25 °C, unless otherwise specified)

Characteristics Curve:

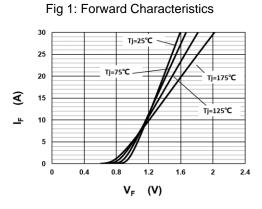


Fig 3: Current Derating

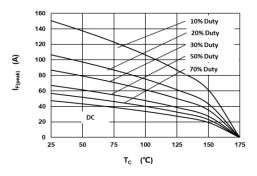


Fig 2: Reverse Characteristics

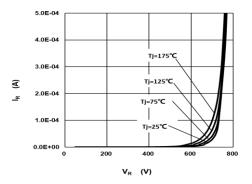


Fig 4: Power Derating

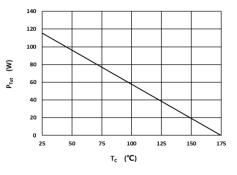
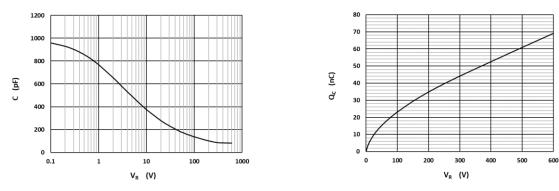


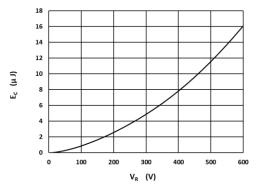


Fig 5: Capacitance vs. Reverse Voltage

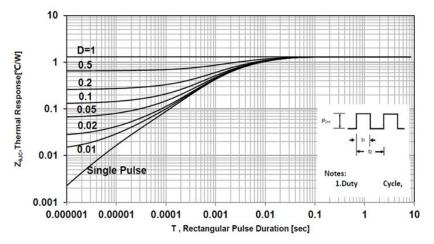
Fig 6: Reverse Charge vs. Reverse Voltage





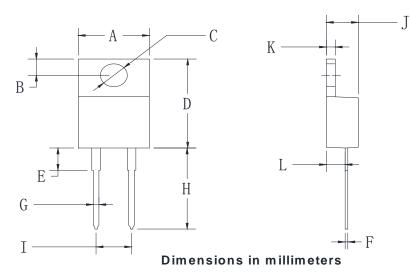








Package Information TO-220H-2L



TO-220H-2L				
Dim	Min	Max		
А	9.5	10.9		
В	2.22	3.27		
С	3.34	4.31		
D	14.5	15.5		
E	3.16	4.46		
F	0.28	0.64		
G	0.68	0.94		
Н	13.06	14.62		
I	4.55	5.60		
J	4.04	5.1		
К	1.14	1.4		
L	2.14	3.19		



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